# 203-361

# Am27S33/27S33A

4,096-Bit (1024x4) Bipolar PROM



# DISTINCTIVE CHARACTERISTICS

- High speed
  Highly reliable, ultra-fast programming Platnum-Silicide
- fuses • High programming yield

- Low-current PNP inputs
- High-current open-collector and three-state outputs
- · Fast chip select

## **GENERAL DESCRIPTION**

The Am27S33 (1024 words by 4 bits) is a Schottky TTL Programmable Read-Only Memory (PROM).

This device is available in three-state (Am27S33) output versions. These outputs are compatible with low-power Schotkky bus standards capable of satisfying the requirements of a vanety of microprogrammable controls, mapping functions, code conversion, or logic replacement. Easy word-depth expansion is facilitated by active LOW ( $\overline{G_1} \& \overline{G_2}$ ) output enables.

# BLOCK DIAGRAM





# PRODUCT SELECTOR GUIDE

Three-State Part Number	Am27	'S33A	Am27\$33				
Address Access Time	35 ns	45 ns	55 ns	70 ns			
Operating Range	с	м	С	м			

	Publication (	t fler.	Amendment
	03226	D	/0
ĺ	Issue Date:	January	1989

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Note: Pin 1 is marked for orientation.

LOGIC SYMBOL



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# ORDERING INFORMATION

**Standard Products** 



Valid Co	mbinations
AM27533	PC, PCB, DC, DCB, FC, FCB, LC, LCB, JC,
AM27S33A	JCB

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Valid Combinations list configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.



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## MILITARY ORDERING INFORMATION

## **APL** Products

AMD products for Aerospace and Defense applications are available in several packages and operating ranges. APL (Approved Products List) products are fully compliant with MIL-STD-883C requirements. The order number (Valid Combination) for APL products is formed by a combination of: a. Device Number b. Speed Option (if applicable) c. Device Class d. Package Type e. Lead Finish AM27S33 <u>/B</u> Α <u>A</u> e. LEAD FINISH A = Hot Solder Dip - d. PACKAGE TYPE V = 18-Pin Ceramic DIP (CD 018) Y = 18-Pin Ceramic Flatpack (CF 018) 2 = 20-Pin Ceramic Leadless Chip Camer (CL 020) c. DEVICE CLASS /B = Class B - b. SPEED OPTION A = 45 ns Blank = 70 ns a. DEVICE NUMBER/DESCRIPTION Am27S33/Am27S33A 1024 x 4 Bipolar PROM Vaild Combinations Valld Combinations Valid Combinations list configurations planned to be AM27S33 /BVA. supported in volume for this device. Consult the local AMD /BYA. /B2A

sales office to confirm availability of specific valid combinations or to check for newly released valid combinations.

#### Group A Tests

#### Group A tests consist of Subgroups 1, 2, 3, 7, 8, 9, 10, 11.

## MILITARY BURN-IN

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Military burn-in is in accordance with the current revision of MIL-STD-883, Test Method 1015, Conditions A through E. Test conditions are selected at AMD's option.

# PIN DESCRIPTION

#### A<sub>0</sub>-A<sub>9</sub> Address inputs

The 10-bit field presented at the address inputs selects one of 1024 memory locations to be read from.

# Q0-Q3 Data Output Port

The outputs whose state represents the data read from the selected memory locations.

G1,G2 Output Enable

Provides direct control of the Q-output buffers. Outputs disabled forces all open-collector outputs to an OFF state and all three-state outputs to a floating or high-impedance state.

Enable = 
$$\overline{G_1} \cdot \overline{G_2}$$
  
Disable =  $\overline{G_1} \cdot \overline{G_2}$   
=  $G_1 + G_2$ 

V<sub>CC</sub> Device Power Supply Pin

The most positive of the logic power supply pins.

GND Device Power Supply Pin The most negative of the logic power supply pins.

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## ABSOLUTE MAXIMUM RATINGS

Storage Temperature
Power Applied 55 to + 125°C
Supply Voltage
DC Voltage Applied to Outputs
(Except During Programming)0.5 V to +VCC Max.
DC Voltage Applied to Outputs
During Programming 21 V
Output Current into Outputs During
Programming (Max Duration of 1 sec) 250 mA
DC Input Voltage05 V to +55 V
DC Input Current30 mA to +5 mA

Stresses above those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to absolute maximum ratings for extended periods may affect device reliability.

# OPERATING RANGES

## Commercial (C) Devices

Ambient Temperature (T<sub>A</sub>) . ... . . . . 0 to +75°C Supply Voltage (V<sub>CC</sub>) . . . +475 V to +525 V

Military (M) Devices\* 

Operating ranges define those limits between which the functionality of the device is guaranteed.

\*Military Product 100% tested at  $T_C = +25^{\circ}C$ , +125°C, and -55°C.

Parameter Symbol	Parameter Description		Test Conditions	Min.	Тур.	Max,	Unit	
VOH	Output HIGH Voltage	V <sub>CC</sub> = Min , IOH VIN = VIH or VI		2.4			v	
VOL	Output LOW Voltage	V <sub>CC</sub> = Min., IOL VIN = VIH or VI				0.45	v	
ViH	Input HIGH Level	Guaranteed inp voltage for all	ut logical HIGH inputs (Note 1)	2.0			v	
VIL	Input LOW Level	Guaranteed inp voltage for all				0.8	v	
4	Input LOW Current	VCC - Max , VII	N = 0.45 V			-0 250	mA	
lн	Input HIGH Current	Vcc = Max., VI	N = 2.7 ¥			25	μA	
ISC (Note 1)	Output Short-Circuit Current	Vcc = Max., Vc	DUT = 0 0 V (Note 2)	- 20		-90	mA	
100	Bower Supply Current	All inputs = GND, COM'L Vcc = Max. MIL					140	mА
100	Power Supply Current						145	
VI	Input Clamp Voltage	Vcc = Min., IIN	= - 18 mA				-12	V
	Output Leakage Current			Vo = Vcc	T		40	
CEX		$V_{CC} = Max.$ $V_{G_1} = 2.4 V$	(Note 1)	V0 = 2.4 V			40	Au
			Vo = 0.4 V			-40		
CIN	Input Capacitance	VIN = 2.0 V @ VCC = 5 V. TA		5		- 5		
COUT	Output Capacitance	VOUT = 2.0 V ( VCC = 5 V, TA		8		pf		

DC CHARACTERISTICS over operating ranges unless otherwise specified (for APL Products, Group A, Subgroups 1, 2, 3 are tested unless otherwise noted)

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Notes: 1. Vit\_ and ViH are input conditions of output tests and are not themselves directly tested. Vit\_ and ViH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment. 2. Not more than one output should be shorted at a time. Duration of the short circuit should not be more than one second. 3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.

SWITCHING CHARACTERISTICS	over operating ranges unless	otherwise specified (for APL Products,
Group A, Subgroups 9, 10, 11 are tested		

				Am27S33A				Am27S33				
				COM'L		MIL		COM'L		MIL		Í
No.	Parameter Symbol	Parameter Description		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
1	TAVQV	Address Valid to Output Valid Access Time	`		35		45		55		70	ns
2	TGVQZ	Delay from Output Enable Valid to Output Hi-Z			20		25		25		30	ns
3	TGVQV	Delay from Output Enable Valid to Output Valid			20		25		25		30	ns

See also Switching Test Circuit.

Notes: 1. Tests are performed with input transition time of 5 ns or less, timing reference levels of 1.5 V, and input pulse levels of 0 to 3.0 V. "Subgroups 7 and 8 apply to functional tests.

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## SWITCHING WAVEFORMS







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